# AC6368B Datasheet

## Zhuhai Jieli Technology Co.,LTD

Version: V1.2

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### **AC6368B Features**

#### **CPU**

- 32-bit DSP supports hardware Float Point Unit (FPU)
- Up to 160MHz programmable processor
- 64Vectored interrupts
- 4 Levels interrupt priority

#### **Bluetooth**

- Compliant with BluetoothV5.4+BR+EDR+BLE specification
- Meet class1 class2 and class3 transmitting power requirement
- Support GFSK and  $\pi/4$  DQPSK all paket types
- Provides +6dbm transmitting power
- receiver with -90dBm sensitivity
- Fast AGC for enhanced dynamic range
- Supports a2dp\avctp\avdtp\avrcp\hfp\spp\smp\att\gap\ gatt\rfcomm\sdp\l2cap profile

### **Temperature**

- Operating temperature: -40°C to +85°C
- Storage temperature: -65°C to +150°C

#### **Peripherals**

- One full speed USB 2.0 OTG controller
- Six multi-function 32-bit timers, support capture and PWM mode
- Three full-duplex basic UART, UART0 and UART1 supports DMA mode
- One hardware IIC interface supports host and device mode
- 10-bit ADC for analog sampling
- External wake up/interrupt on all GPIOs

#### **PMU**

- Low voltage LDO for internal digital and analog circuit supply
- **3uA current consumption in the soft-off mode**
- Built-in LDO for the core, I/O, Bluetooth and flash
- **VBAT** is 2.2V to 5.5V
- **VDDIO** is 2.2V to 3.4V

#### **Packages**

SOP8

### **Applications**

Bluetooth IOT

### 1. Pin Definition

### 1.1 Pin Assignment

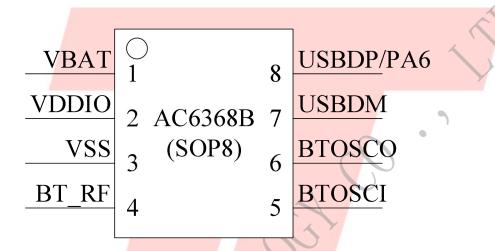


Figure 1-1 AC6368B Package Diagram

### 1.2 Pin Description

Table 1-1 AC6368B Pin Description

PIN NO.	Name	I/O Type	Drive (mA)	Function	Other Function
1	VBAT	P	/		Battery Power Supply
2	VDDIO	P	/		IO Power 3.3v
3	VSS	P	/	/	Ground
4	BT_RF	/			BT Antenna
5	BTOSCI	I	/		BT OSC In
6	BTOSCO	О	1/	4	BT OSC Out
7	USBDM	I/O		USB Negative Data (pull down)	IIC_SDA_A: IIC SDA(A); SPI2_DOB: SPI2 Data Out(B); ADC14: ADC Input Channel 14; UART1RXD: Uart1 Data In(D);
8	USBDP	I/O		USB Positive Data (pull down)	IIC_SCL_A: IIC SCL(A); SPI2_CLKB: SPI2 Clock(B); ADC13: ADC Input Channel 13; UART1TXD: Uart1 Data Output(D);
	PA6	I/O		GPIO	ADC4: ADC Input Channel 4; CAP4: Timer4 Capture; UART0RXA: Uart0 Data In(A);

### 2, Electrical Characteristics

### 2.1 Absolute Maximum Ratings

Table 2-1

Symbol	Parameter	Min	Max	Unit
Topt	Operating temperature	-40	+85	$^{\circ}\mathrm{C}$
Tstg	Storage temperature	-65	+150	°C
VBAT	Supply Voltage	-0.3	5.5	V
V <sub>3.3IO</sub>	3.3V IO Input Voltage	-0.3	3.6	V

Note: The chip can be damaged by any stress in excess of the absolute maximum ratings listed below

### 2.2 Recommended Operating Conditions

Table 2-2

Symbol	Parameter	Min	Тур	Max	Unit	2	Test Conditions
VBAT	Voltage Input	2.2	3.7	5.5	V	<b>)</b>	
$V_{\mathrm{VDDIO}}$	Voltage Input	/_	3.0		V		

### 2.3 IO Input/Output Electrical Logical Characteristics

Table 2-3

IO input ch	aracteristics					
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
V <sub>IL</sub>	Low-Level Input Voltage	-0.3	-	0.3* VDDIO	V	VDDIO = 3.3V
$V_{IH}$	High-Level Input Voltage	0.7* VDDIO	-	VDDIO+0.3	V	VDDIO = 3.3V
IO output c	haracteristics					and the second s
$V_{\mathrm{OL}}$	Low-Level Output Voltage	_	_	0.33	V	VDDIO = 3.3V
V <sub>OH</sub>	High-Level Output Voltage	2.7	_	_	V	VDDIO = 3.3V

### 2.4 Internal Resistor Characteristics

Table 2-4

Port	General Output	High Drive	Internal Pull-Up Resistor	Internal Pull-Down Resistor	Comment
PA6	8mA	24mA	10K	10K	1、USBDM & USBDP default pull down
USBDP	4mA		1.5K	15K	2. internal pull-up/pull-down resistance   accuracy
USBDM	4mA	-	180K	15K	±20%

### 2.5 BT Characteristics

#### 2.5.1 Transmitter

**Basic Rate** 

Table 2-5

Paramete	er	Min	Тур	Max	Unit	<b>Test Conditions</b>
RF Transmit I	Power	- 4	4	6	dBm	
RF Power Contro	ol Range		20	-	dB	25°C,
20dB Bandwidth			950	-	KHz	Power Supply
In-band spurious	$F=F_0\pm 1MHz$	-	-20	-	dBm	VBAT=3.7V
Emissions	$F=F_0\pm 2MHz$	7/	-45	7	dBm	2441MHz
(BQB Test Mode	$F=F_0\pm 3MHz$	/-/	-35	/-	dBm	DH5
RF_Tx Power=4dBm)	$F=F_0\pm>3MHz$	/ -	-45	-	dBm	

**Enhanced Data Rate** 

Table 2-6

Paramete	Parameter			Max	Unit	Test Conditions
Relative Po	wer	-	-1	-	dB	
π/4 DQPSK	DEVM RMS	-	4	-	%	25°C,
	DEVM 99%	-	10	-	%	Power Supply
Modulation Accuracy	DEVM Peak	-	7	-	%	***
In-band spurious	$F=F_0\pm 1MHz$	-	-4	-	dBm	VBAT=3.7V
Emissions	F=F <sub>0</sub> ±2MHz	-	-30	-	dBm	2441MHz
(BQB Test Mode	F=F <sub>0</sub> ±3MHz	-	-30	-	dBm	2DH5
RF_Tx Power=4dBm)	$F=F_0\pm>3MHz$	-	-37	-	dBm	

### 2.5.2 Receiver

**Basic Rate** 

**Table 2-7** 

Paramete	Parameter			Max	Unit	Test Conditions
Sensitivit	Sensitivity			-	dBm	
Co-channel Interferer	nce Rejection	-	6	-	dB	25°C,
	+1MHz	-	-6	-	dB	Power Supply
	-1MHz	-	-8	-	dB	4
Adjacent Channel	+2MHz	-	-17	-	dB	VBAT=3.7V
selectivity C/I	-2MHz	-/	-21	//-	dB	2441MHz
	+3MHz	4	-15	/-	dB	DH5
	-3MHz	-	-31	-	dB	

### **Enhanced Data Rate**

Table 2-8

Paramete	er	Min	Тур	Max	Unit	Test Conditions
Sensitivit	Sensitivity		-90	(-)	dBm	
Co-channel Interferen	ace Rejection	-	9	<u>)-</u>	dB	25°C,
	+1MHz	-	-10	) _	dB	Power Supply
	-1MHz	-(^)	-13	-	dB	
Adjacent Channel	+2MHz		-11	-	dB	VBAT=3.7V
selectivity C/I	-2MHz		-21	- /	dB	2441MHz
	+3MHz	7	-13	-/-	dB	2DH5
	-3MHz	<b>/-</b> /	-40	-	dB	

### 2.5.3 BLE

#### 1M Data Rate

**Table 2-9** 

Parameter		Min	Тур	Max	Unit	Test Conditions			
Sensitivit	Sensitivity		-91	-	dBm				
RF Transmit I	Power	-	6	-	dBm				
In-band Spurious	M-N =2MHz	-	-41	-	dBm				
Emission	M-N ≥3MHz	-	-40	-	dBm	25°C			
	Δfl avg	-	250	-	KHz	Power Supply			
Modulation Characteristics	Δf2 99%	-	210	/- /-	KHz	VBAT=3.7V			
0.1.4.2.1.2.1.2.1.2	Δflavg/Δf2avg	4	0.9	-	1	2440MHz			
Carrier Frequency Offset		-50	- /	+50	KHz				
Frequency Drift		-25	-/	+25	KHz				
Frequency Dri	ft Rate	-5	7/	+5.	KHz/50us				
·		·	11			·			

#### 2M Data Rate

**Table 2-10** 

Paramete	r	Min	Тур	Max	Unit	Test Conditions
Sensitivity	Sensitivity		-89	- )	dBm	
RF Transmit P	ower	-6	6	- /	dBm	
	M-N =4 <mark>MHz</mark>		-45	- 7	dBm	
In-band Spurious Emission	M-N =5MHz		-45	-/	dBm	25°C
	M-N ≥6MHz	-///	-45	y <u>-</u>	dBm	Power Supply
26.11.0	Δfl avg	-	500	-	KHz	
Modulation Characteristics	Δf2 99%	/ -	430	-	KHz	VBAT=3.7V
Characteristics	Δflavg/Δf2avg	/ <sub>-</sub>	0.9	-	/	2440MHz
Carrier Frequency Offset		-50	-	+50	KHz	
Frequency Drift		-25	-	+25	KHz	
Frequency Drif	t Rate	-5	-	+5	KHz/50us	

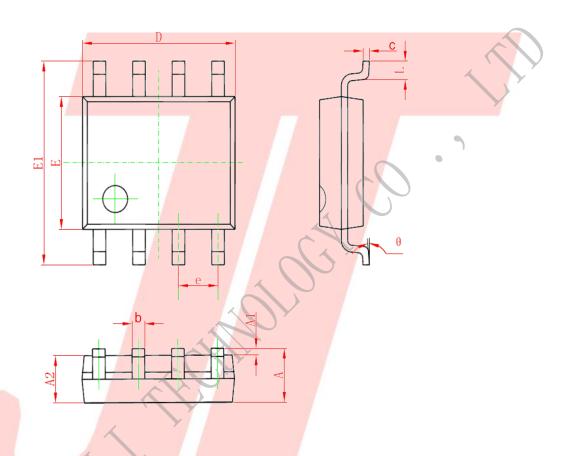
### **Long Range**

**Table 2-11** 

Parameter	Min	Тур	Max	Unit	Test Conditions
Sensitivity LE 125K(S8)	-	-99	-	dBm	VBAT=3.7V,25°C
Sensitivity LE 500K(S2)	-	-95	-	dBm	2440MHz

## 3. Package Information

### 3.1 SOP8



Symbol	Dimension In Millimeters		Dimension In Inches	
	Min	Max	Min	Max
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
С	0.170	0.250	0.007	0.010
D	4.700	5.100	0.185	0.201
Ш	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
е	1.27TYP		0.050TYP	
Ш	0.400	1.270	0.016	0.050
θ	00	8 <sup>0</sup>	00	8 <sup>0</sup>

Figure 3-1 AC6368B Package

## 4. Revision History

Date	Revision	Description	
2020.07.03	V1.0	Initial Release	
2022.07.19	V1.1	Update Bluetooth Feature	
2024.03.06	V1.2	Update Bluetooth Feature, Add BLE Parameter	

